

GL494

PWM CONTROL CIRCUIT

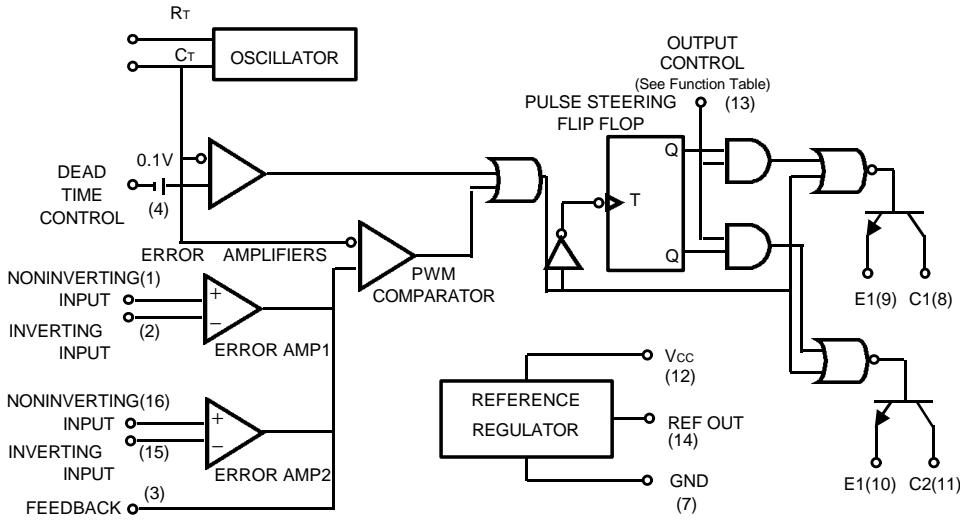
Description

The GL494 incorporates on a single monolithic chip all the functions required in the construction of a pulse-width-modulation control circuit. Designed primarily for power supply control, the GL494 contains an on-chip 5-volt regulator, two error amplifiers, adjustable oscillator, dead-time control comparator, pulse-steering flip-flop, and output-control circuitry. The uncommitted output transistors provide either common-emitter or emitter-follower output capability. Push-pull or single-ended output operation may be selected through the output-control function. The architecture of the GL494 prohibits the possibility of either output being pulsed twice during push-pull operation.

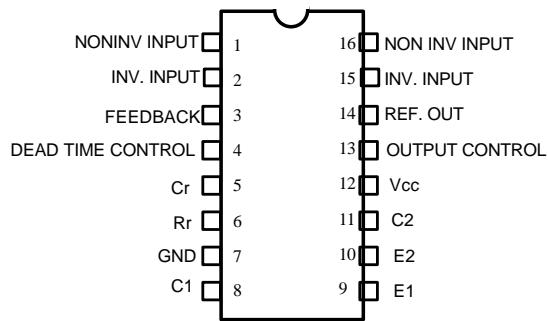
Features

- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200mA Sink or Source
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Internal Regulator Provides a Stable 5V Reference Supply
- Variable Dead-Time Provides Control Over Total Range

Block Diagram



Pin Configuration



Function Table

Output Control	Output Function
Grounded	Single-ended or Parallel Output
At V_{ref}	Normal Push-Pull Operation

Absolute Maximum Ratings

Supply Voltage, V _{CC}	41	V
Amplifier Input Voltage	V _{CC} +0.3	V
Collector Output Voltage	41	V
Continuous Total dissipation at (or below) 25 °C	1000	mW
Operating Free-Air Temperature Range	-20 to 85	°C
Storage Temperature Range	-65 to 150	°C
Collector Output Current	250	mA

Recommended Operation Conditions

PARAMETER	MIN	MAX	UNIT
Supply Voltage, V _{CC}	7	40	V
Amplifier Input Voltage, V _I	-0.3	V _{CC} -2	V
Collector Output Voltage, V _O		40	V
Collector Output Current (Each Transistor)		200	mA
Current Into Feed back Terminal		0.3	mA
Timing Capacitor, C _T	0.47	10,000	nF
Timing Resistor, R _T	1.8	500	KΩ
Oscillator Frequency	1	300	KHz
Operating Free-Air Temperature	-20	85	°C

Electrical Characteristics (Temperature -20 ~ 85°C , V_{CC} =15V, f=10KHz)

Reference Section

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Output voltage (V _{ref})	I _O = 1mA	4.75	5	5.25	V
Input regulation	V _{CC} = 7V to 40V, T _A = 25°C		2	25	mV
Output regulation	I _O = 1 to 10mA, T _A = 25°C		1	15	mV
Output Voltage change with temperature	T _A = -20°C to 85°C		0.2	1	%
Short-circuit Output current(2)	V _{ref} = 0		35		mA

Oscillator Section

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Frequency	C _T = 0.01μF , R _T = 12kΩ		10		KHz
Standard deviation of frequency (3)	All values of V _{CC} , C _T ,R _T ,T _A Constant		10		%
Frequency change with Voltage	V _{CC} = 7V to 40V, T _A = 25°C		0.1		%
Frequency change with temperature	C _T = 0.01μF , R _T = 12kΩ T _A = -20°C to 85°C			2	%

Dead Time Control Section

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Input bias current (pin 4)	V _I =0 to 5.25V		-2	-10	μA
Maximum duty cycle, Each output	V _{I(pin4)} =0V	45			%
Input threshold voltage (pin 4)	Zero duty cycle		3	3.3	V
	Maximum duty cycle	0			V

Error Amp Sections

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Input offset voltage	V _{O(PIN3)} = 2.5V		2	10	mV
Input offset current	V _{O(PIN3)} = 2.5V		25	250	nA
Input bias current	V _{O(PIN3)} = 2.5V		0.2	1	μA
Common-mode input voltage range	V _{CC} = 7V to 40V	LOW	-0.3		V
		HIGH	V _{CC} -2		
Open-loop voltage Amplification	ΔV _O = 3V, V _O = 0.5 to 3. 5V	70	95		dB
Unity-gain bandwidth			800		KHz
Common-mode rejection ratio	V _{CC} = 40V, T _A = 25°C	65	80		dB
Output sink current (pin 3)	V _{ID} = -15mV to -5V, V _{O(pin3)} = 0.7V	0.3	0.7		mA
Output source current (pin 3)	V _{ID} = 15mV to 5V, V _{O(pin3)} = 3.5V	-2			mA

PWM Comparaor Section

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Input threshold voltage (pin 3)	Zero duty cycle		4	4.5	V
Input sink current (pin 3)	V _{O(pin3)} = 0.7V	0.3	0.7		mA

Switching Characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Output Voltage rise time	Common-emitter configuration, See Test Circuit 3		100	200	ns
Output Voltage fall time			25	100	ns
Output Voltage rise time	Emitter-follower configuration, See Test Circuit 4		100	200	ns
Output Voltage fall time			40	100	ns

Output Section

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Collector off-state current	$V_{CE} = 40V, V_{CC} = 40V$		2	100	mA
Emitter off-state current	$V_{CC} = V_C = 40V, V_E = 0$			-100	mA
Collector-emitter Saturation voltage	Common-emitter	$V_E = 0, I_C = 200mA$	1.1	1.3	V
	Emitter-follower	$V_C = 15V, I_E = -200mA$	1.5	2.5	
Output control input current	$V_I = V_{ref}$			3.5	mA

Total Device

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Standby supply current	All other inputs & Outputs open	$V_{CC} = 15V$	6	10	mA
		$V_{CC} = 40V$	9	15	mA
Average supply current	$V_{(pin4)} = 2V$ See Test circuit 1		7.5		mA

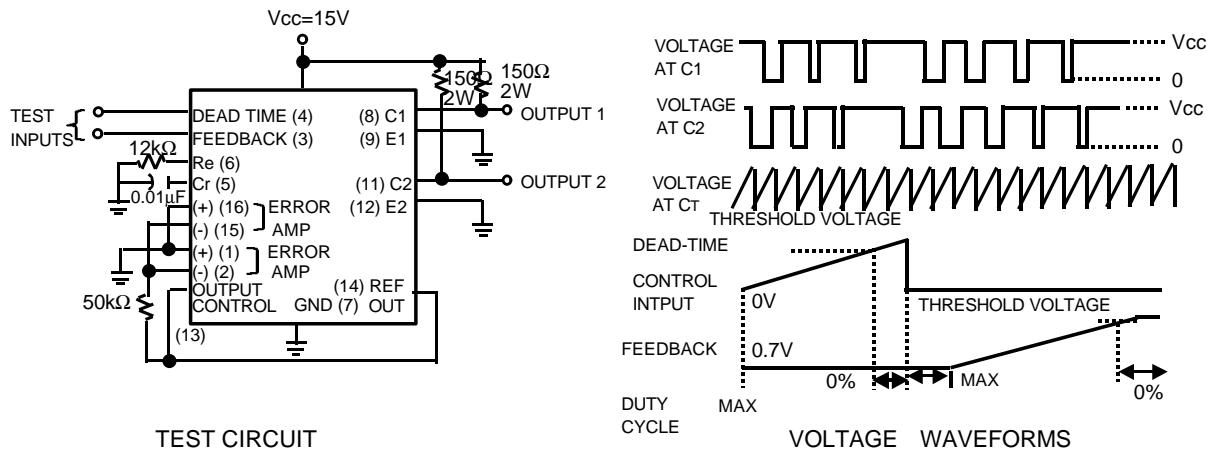
Notes:

- (1) All typical values except for temperature coefficients are at $T_A = 25^\circ C$
- (2) Duration of the short circuit should not exceed one second.
- (3) Standard deviation is a measure of the statistical distribution about the mean as derived from the formula

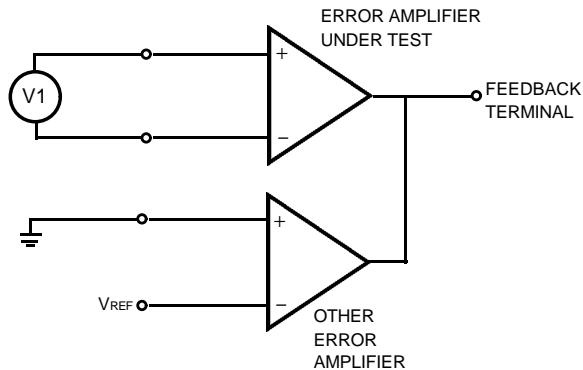
$$\sigma = \sqrt{\frac{\sum_{n=1}^N (X_n - \bar{X})^2}{N - 1}}$$

Parameter Measurement Information

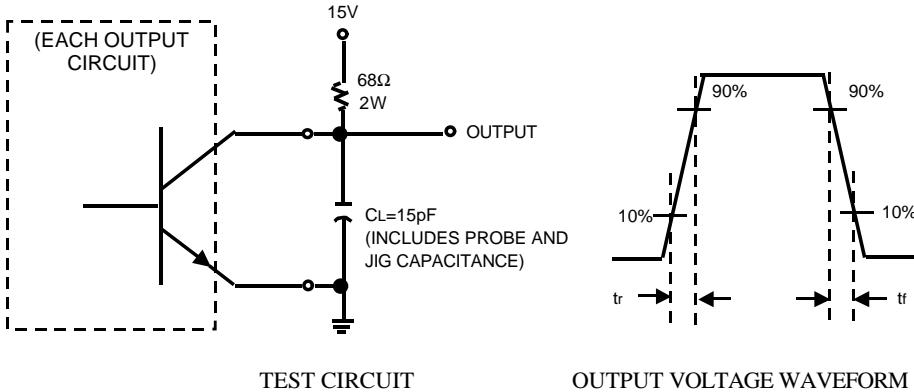
1. Dead time and Feedback Control



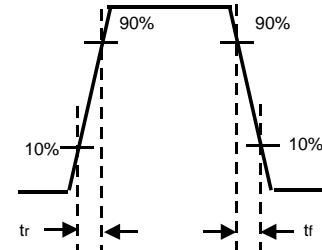
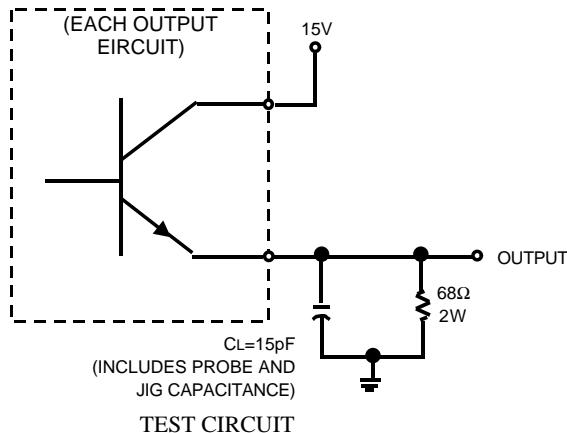
2. Error Amplifier Characteristics



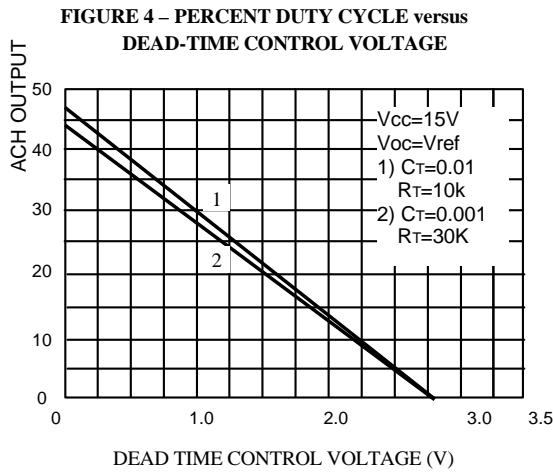
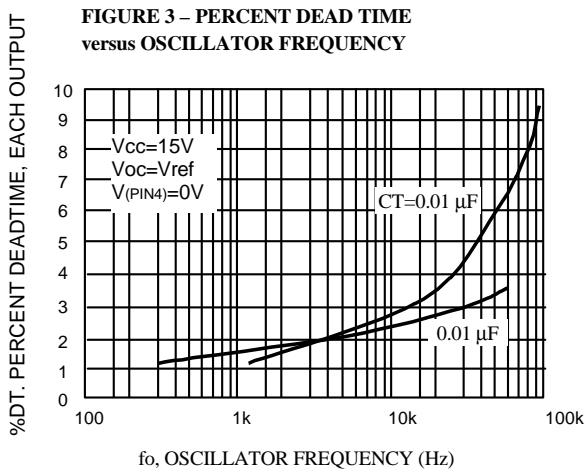
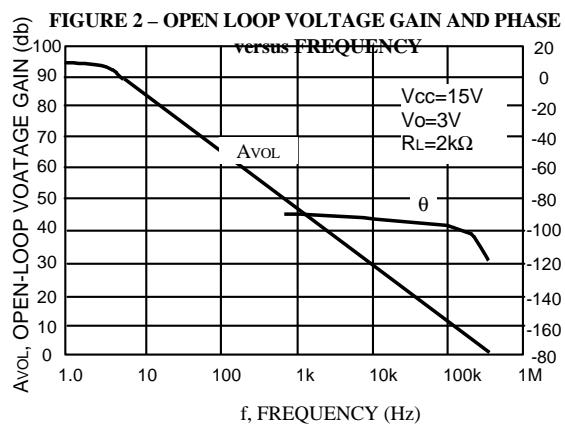
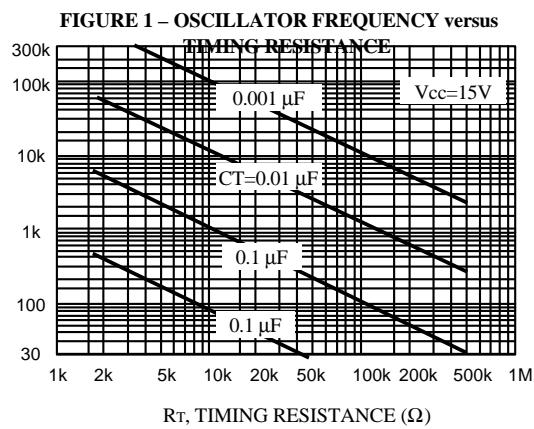
3. Common-Emitter Configuration



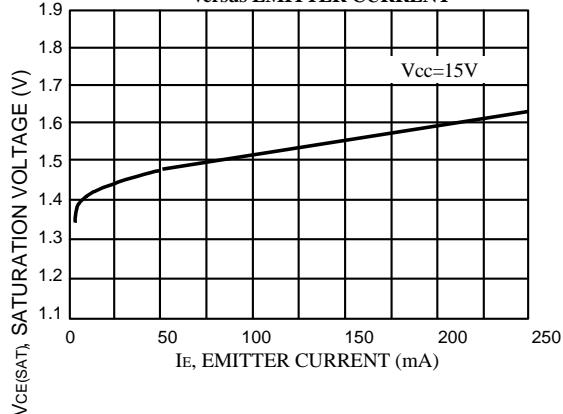
4. Emitter-Follower Configuration



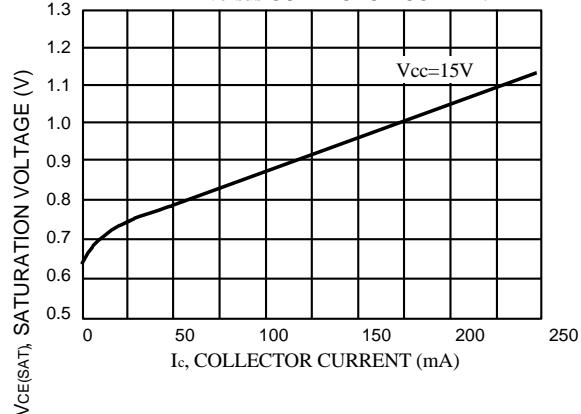
Typical Performance Curves



**FIGURE 5 – Emitter-Follower Configuration
OUTPUT-SATURATION VOLTAGE
versus Emitter Current**



**FIGURE 6 – COMMON-EMITTER CONFIGURATION
OUTPUT-SATURATION VOLTAGE
versus COLLECTOR CURRENT**



**FIGURE 7 – STANDBY-SUPPLY CURRENT
versus SUPPLY VOLTAGE**

